

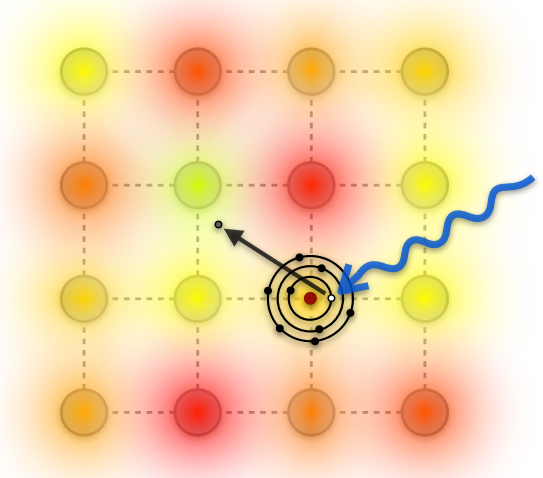
A two-step model for studying ionization potential depression in dense plasmas

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Average Atom Models for Warm Dense Matter

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Collaboration

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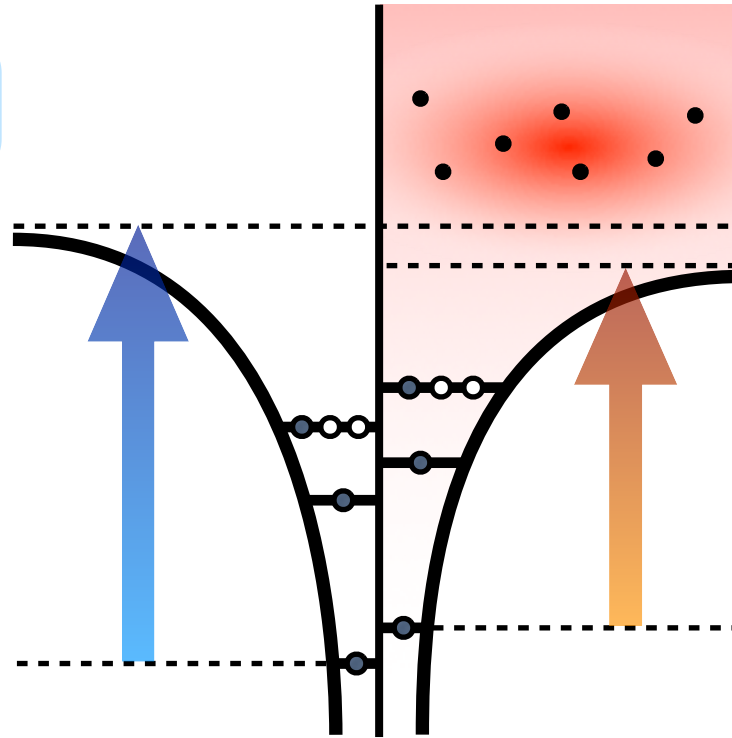


John Bekx

Ionization Potential Depression (IPD)

isolated atom

- Coulomb potential by the nucleus
- screening by bound electrons



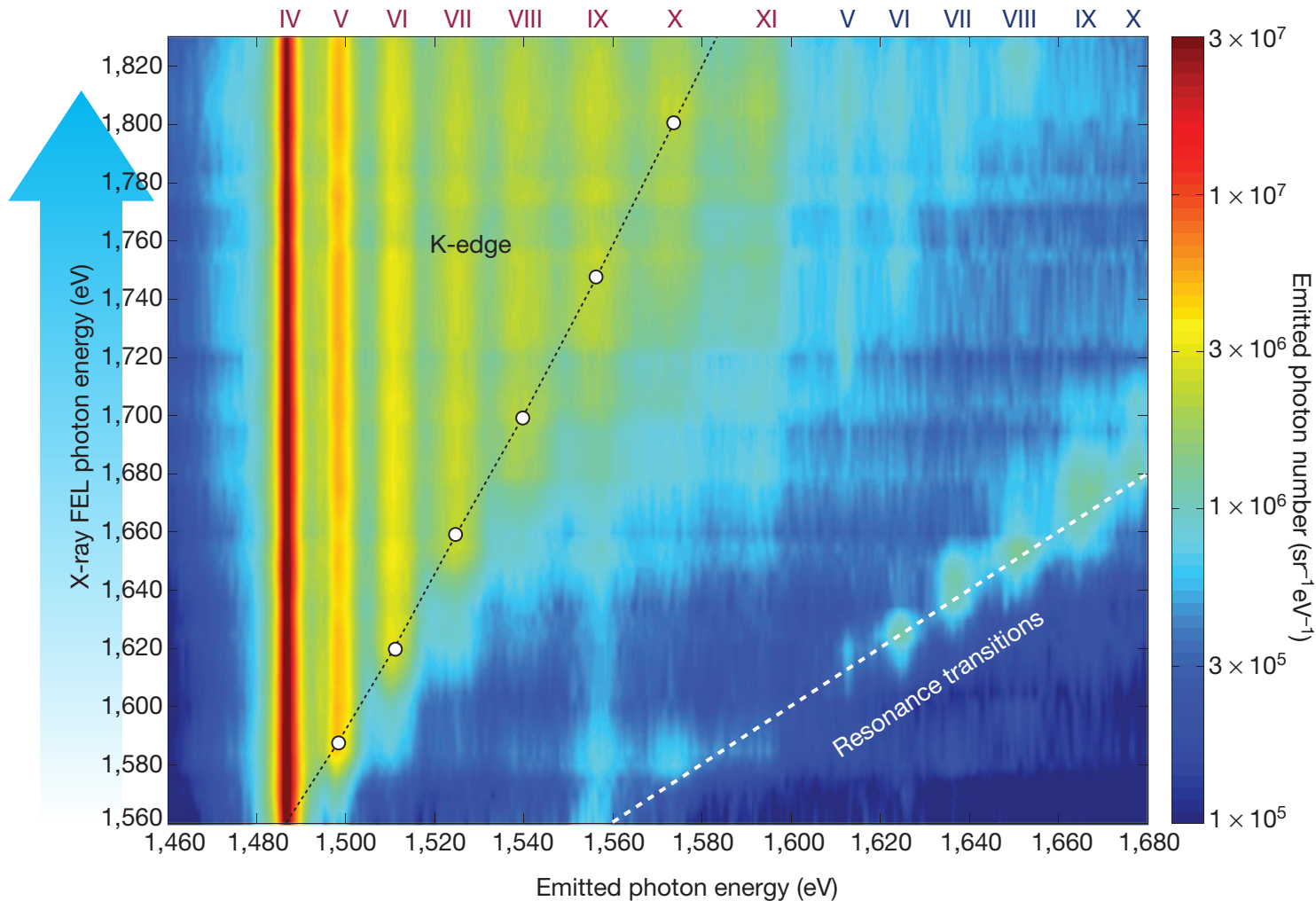
solid / plasma

Dense environment
+ screening by free electrons
+ pressure ionization
→ IP lowering

One of the most fundamental physics for atomic processes in a dense plasma

$$\text{IPD: } \Delta E_i = \text{IP}_i^{\text{iso}} - \text{IP}_i^{\text{pla}}$$

Warm dense Al plasma (XFEL experiment)



$T < 200$ eV
solid density
(2.7 g/cm³)

Vinko *et al.*,
Nature **482**, 59
(2012);

Ciricosta *et al.*,
Phys. Rev. Lett.
109, 065002
(2012).

Two-step model: overview

- > Two-step model based on
 - Quantum-mechanical calculation: Hartree-Fock-Slater method
 - muffin-tin approximation
 - pseudocontinuum calculation

First step

Average-atom
calculation

Second step

fixed-configuration
calculation

Son, Thiele, Jurek, Ziaja & Santra, *Phys. Rev. X* **4**, 031004 (2014).

Hartree-Fock-Slater / muffin-tin potential

- > Solve the Schrödinger equation (SE)

$$\hat{H} = -\frac{1}{2}\nabla^2 + V(\mathbf{r})$$

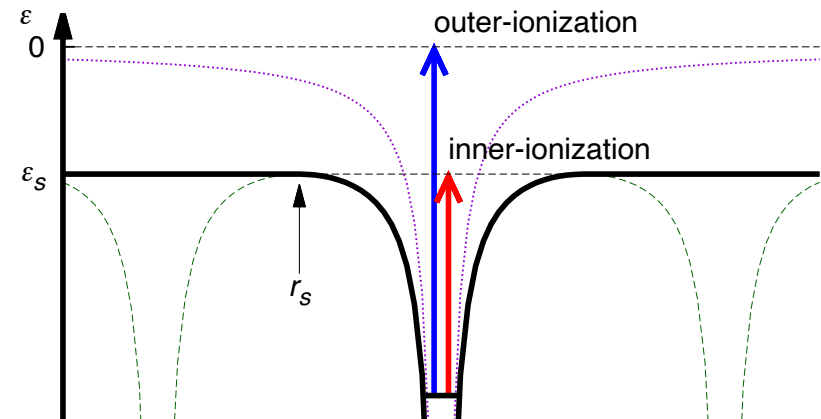
$$\hat{H}\psi(\mathbf{r}) = \varepsilon\psi(\mathbf{r})$$

- > HFS potential inside the WS radius / muffin-tin flat potential outside

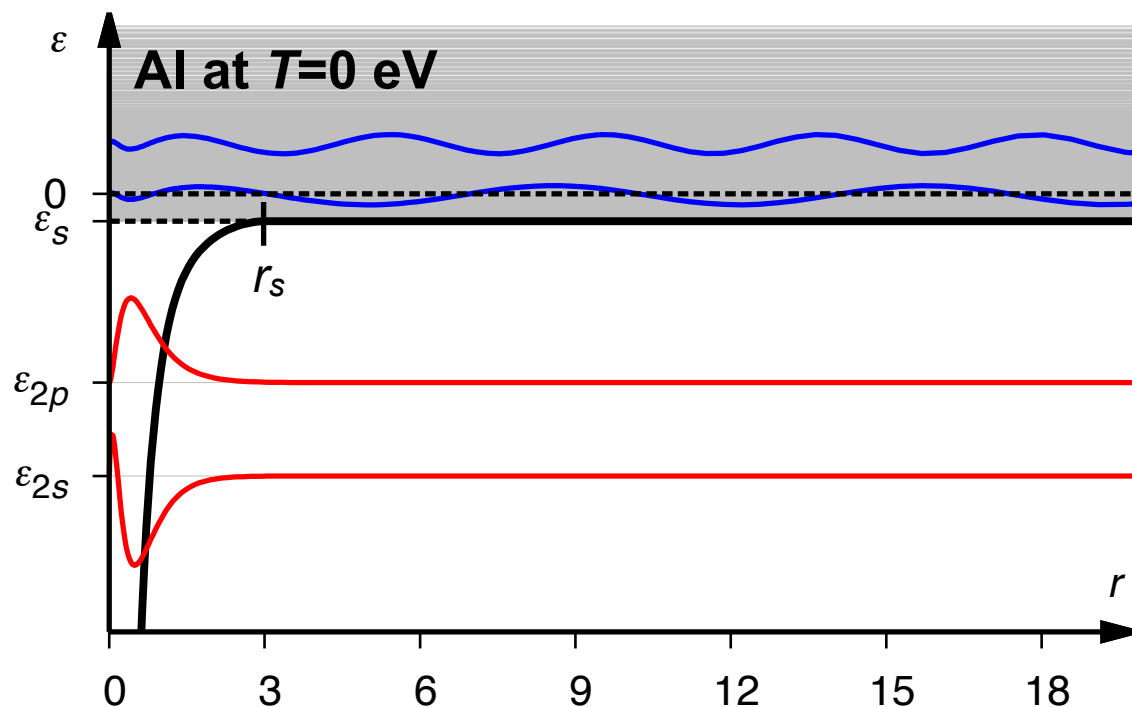
$$V(\mathbf{r}) = \begin{cases} -\frac{Z}{r} + \int_{r' \leq r_s} d^3r' \frac{\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} + V_x[\rho(\mathbf{r})] & \text{for } r \leq r_s \\ V(r_s) (= \varepsilon_s) & \text{for } r > r_s \end{cases}$$

- > Slater exchange potential: $V_x[\rho(\mathbf{r})] = -\frac{3}{2} \left[\frac{3}{\pi} \rho(\mathbf{r}) \right]^{1/3}$

- > Spherical averaging: $\left[-\frac{1}{2} \frac{d^2}{dr^2} + \frac{l(l+1)}{2r^2} + V(r) \right] u_{nl}(r) = \varepsilon_{nl} u_{nl}(r)$



Continuum-state calculation



- $\epsilon \geq \epsilon_s$: pseudocontinuum
- $\epsilon < \epsilon_s$: bound

$r_s \sim 3$ a.u.

$r_{\max}=100$ a.u. in calculation

- non-uniform radial grid: $N_r=200$, $0 \leq l \leq 30 \rightarrow 6200$ (n,l) -eigenstates
- no boundary condition at all at r_s
- no distinction b/w bound and continuum states
- pseudocontinuum approach: widely used in strong-field atomic physics

cf) Gérard Massacrier's talk
and *PRR* **3**, 023026 (2021).

Finite-temperature calculation

- > Grand-canonical ensemble at a finite temperature T
- > Solve SE with $\hat{H} = -\frac{1}{2}\nabla^2 + V[\rho(\mathbf{r}, T)]$
- > Electronic density (bound & continuum) $\rho(\mathbf{r}, T) = \sum_p |\psi_p(\mathbf{r})|^2 \bar{n}_p(\mu, T)$
- > Fermi-Dirac distribution $\bar{n}_p(\mu, T) = \frac{1}{e^{(\varepsilon_p - \mu)/T} + 1}$
- > Chemical potential $Z - \sum_p \left(\int_{r \leq r_s} d^3r |\psi_p(\mathbf{r})|^2 \right) \bar{n}_p(\mu, T) = 0$
- > Assumption: thermalized hot electrons; cold ions
- > Input parameters: element (Z), temperature (T), and ion density (via r_s)

This AA model has been implemented within **XATOM**

Son *et al.*, *Phys. Rev. A* **83**, 033402 (2011); Jurek *et al.*, *J. Appl. Cryst.* **49**, 1048 (2016);
<http://www.desy.de/~xraypac>

Benchmark calculations of XATOM-AA

- > For Al at $T=0$ eV, avg. Q is +3 and Fermi E is 8.0 eV (EXP: 11.7 eV).
- > For Fe at $T=0$ eV, avg. Q is +8 and Fermi E is 7.9 eV (EXP: 11.1 eV).
- > For Al at low temperatures,

Level	T=10 eV, solid density		T=5 eV, 0.1×solid density		
	Present	Sahoo(2008)	Present (HFS)	Present (LDA)	Johnson(2006)
1s	−1530.1	−1495.0	−1547.3	−1501.8	−1501.8
2s	−102.5	−101.2	−119.6	−108.2	−108.3
2p	−64.9	−63.9	−82.0	−70.9	−71.0
3s		−6.3	−8.6	−7.0	−7.0
3p			−2.5	−1.4	−1.5
μ	−1.5		−11.1	−10.3	−10.4
avg. Q	+3.01	+2.38	+1.34	+1.45	+1.49

Sahoo *et al.*, *Phys. Rev. E* **77**, 046402 (2008); Johnson *et al.*, *JQSRT* **99**, 327 (2006).

Average-atom results for Al plasma

- > Self-consistently determined: orbitals, orbital energies, electron density, muffin-tin flat potential ε_s , and chemical potential μ

Al	T	$\bar{Q}$	ε_{1s}	$\dots$	ε_s	μ
solid density $Z=13$ $n_i=2.7 \text{ g/cm}^3$	10	+3.01	-1541.14		-11.03	-12.57
	30	+3.95	-1579.28		-12.46	-58.67
	40	+4.83	-1606.37		-13.19	-85.66
	60	+5.67	-1657.70		-14.33	-145.43
	80	+6.87	-1702.23		-15.15	-211.69

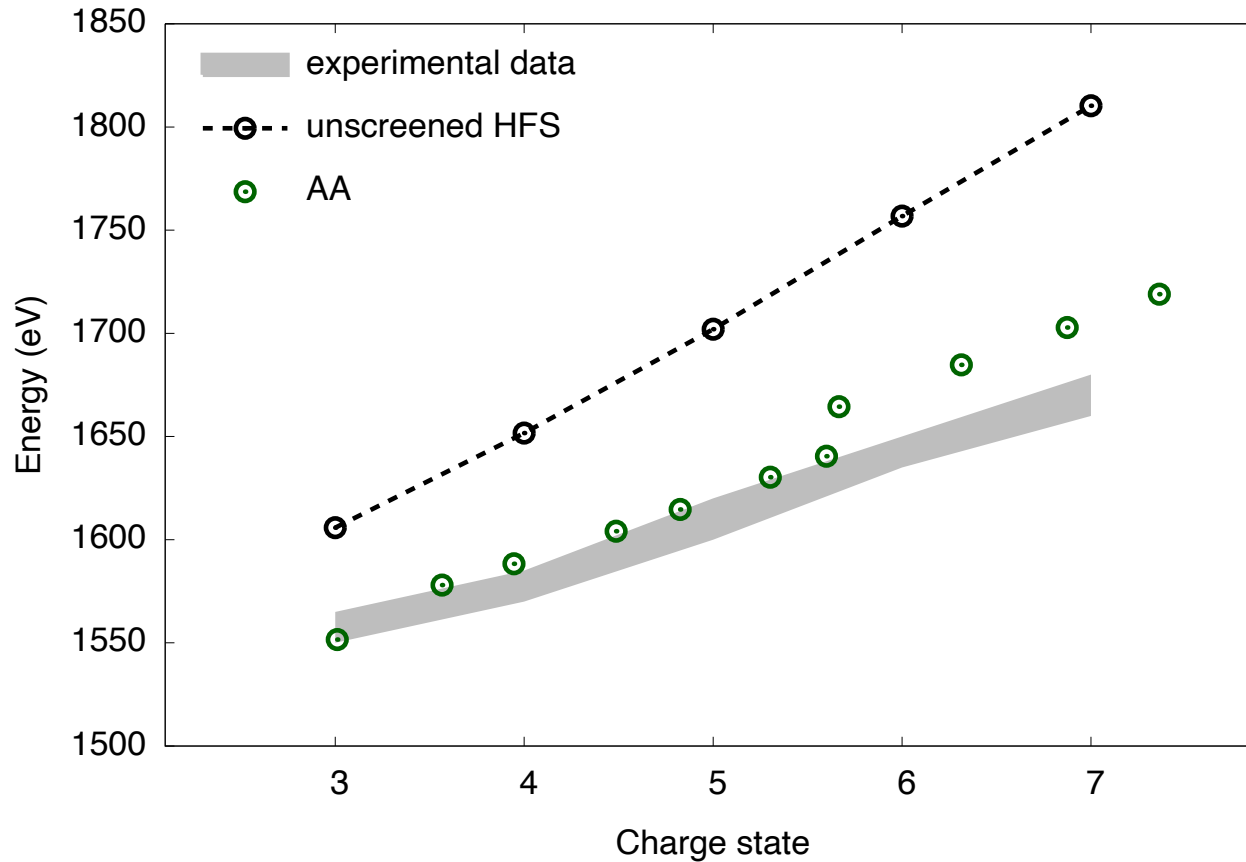
ensemble-averaged charge and orbital energies

Ionization potential calculation:

$$\text{IP} = \begin{cases} \varepsilon_s - \varepsilon_{1s} & (\mu \leq \varepsilon_s) \\ \mu - \varepsilon_{1s} & (\mu > \varepsilon_s) \end{cases}$$

cf) Suxing Hu's talk and *PRL* **119**, 065001 (2017).

Ionization potential with AA only

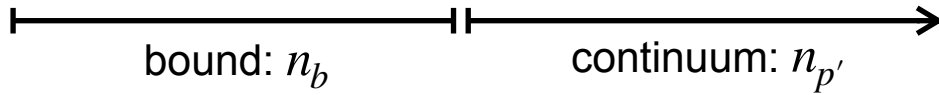


Problem with ensemble-averaged charges? No such things in experiment!

AA as first step: more than average

AI at $T=80$ eV

Q	Configuration	Probability	E_K	E_{Ka}
+5	$1s^2 2s^1 2p^4 3s^0 3p^1$	0.0193	1618.3	1497.7
	$1s^2 2s^2 2p^3 3s^0 3p^1$	0.0187	1623.1	1500.3
	$1s^2 2s^2 2p^4 3s^0 3p^0$	0.0174	1578.7	1486.7
+6	$1s^2 2s^1 2p^3 3s^0 3p^1$	0.0376	1658.1	1511.6
	$1s^2 2s^1 2p^4 3s^0 3p^0$	0.0349	1618.3	1497.7
	$1s^2 2s^2 2p^3 3s^0 3p^0$	0.0339	1623.1	1500.3
	$1s^2 2s^2 2p^2 3s^0 3p^1$	0.0205	1663.5	1514.5
	$1s^2 2s^1 2p^3 3s^1 3p^0$	0.0139	1656.0	1511.3
+7	$1s^2 2s^1 2p^3 3s^0 3p^0$	0.0681	1666.3	1512.8
	$1s^2 2s^1 2p^2 3s^0 3p^1$	0.0413	1705.4	1527.8
	$1s^2 2s^2 2p^2 3s^0 3p^0$	0.0371	1671.9	1515.8
	$1s^2 2s^0 2p^3 3s^0 3p^1$	0.0189	1699.3	1524.5
	$1s^2 2s^0 2p^4 3s^0 3p^0$	0.0175	1660.9	1509.9
	$1s^2 2s^1 2p^2 3s^1 3p^0$	0.0153	1705.4	1527.9
	$1s^2 2s^2 2p^1 3s^0 3p^1$	0.0120	1711.7	1531.2
+8	$1s^2 2s^1 2p^2 3s^0 3p^0$	0.0747	1718.7	1530.0
	$1s^2 2s^0 2p^3 3s^0 3p^0$	0.0342	1712.3	1526.7
	$1s^2 2s^1 2p^1 3s^0 3p^1$	0.0241	1758.5	1546.5
	$1s^2 2s^2 2p^1 3s^0 3p^0$	0.0217	1725.1	1533.4
	$1s^2 2s^0 2p^2 3s^0 3p^1$	0.0207	1751.6	1542.9
+9	$1s^2 2s^1 2p^1 3s^0 3p^0$	0.0437	1775.1	1549.6
	$1s^2 2s^0 2p^2 3s^0 3p^0$	0.0375	1768.0	1545.9
	$1s^2 2s^0 2p^1 3s^0 3p^1$	0.0121	1808.2	1564.1
+10	$1s^2 2s^0 2p^1 3s^0 3p^0$	0.0219	1827.4	1568.1
	$1s^2 2s^1 2p^0 3s^0 3p^0$	0.0106	1835.2	1572.1

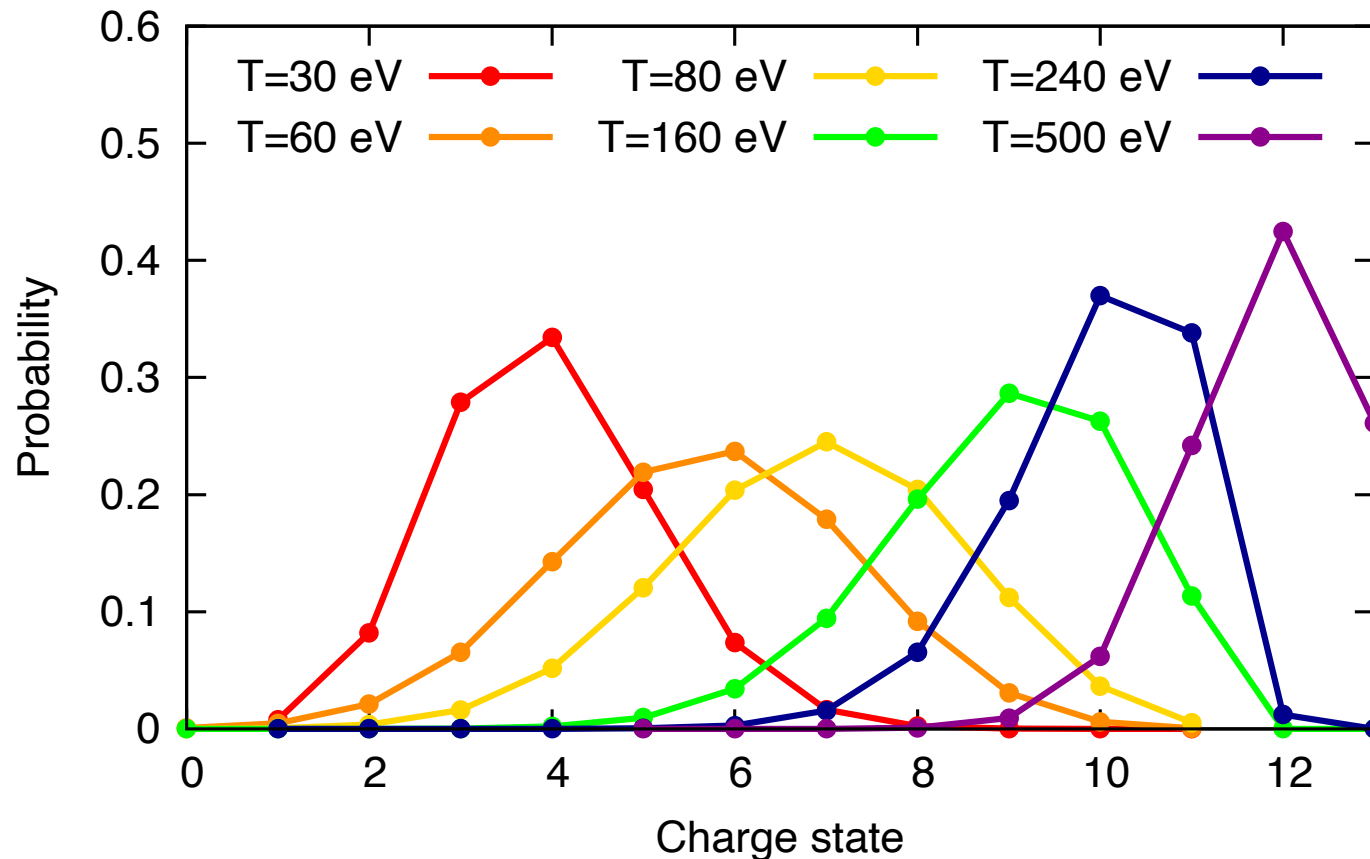
$1s^{n_1} 2s^{n_2} 2p^{n_3} 3s^{n_4} 3p^{n_5} 3d^{n_6} 4s^{n_7} 4p^{n_8} \dots$


From the grand-canonical ensemble, probability distributions calculated for given bound-state configurations

$$\begin{aligned}
 P[n_b] &= \sum_{\{n_p\}=\{n_b; n_{p'}\}} P\{n_p\} \\
 &= \prod_b^{\text{bound}} \frac{e^{-(\varepsilon_b - \mu)n_b/T}}{1 + e^{-(\varepsilon_b - \mu)/T}}
 \end{aligned}$$

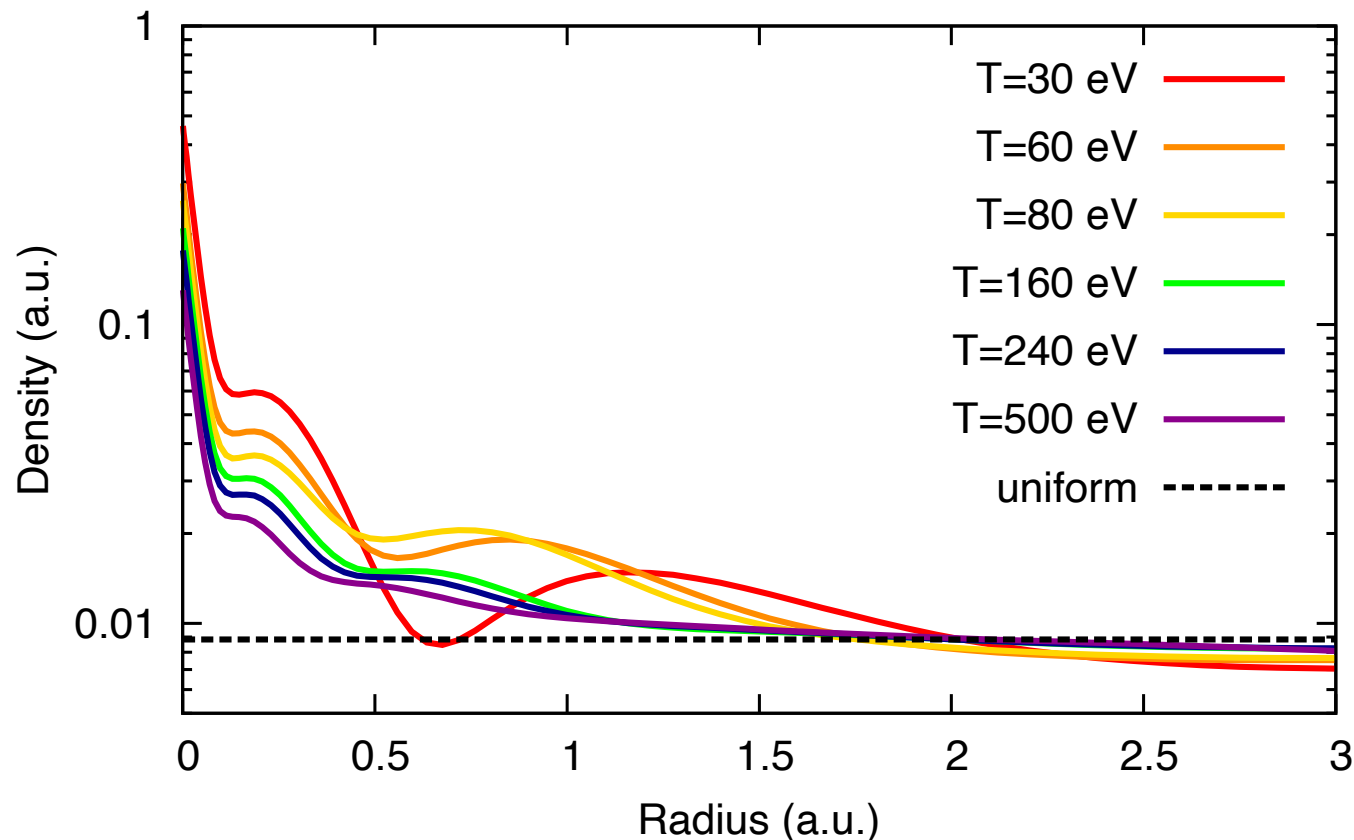
Pei & Chang, *JQSRT* **64**, 15 (2000).

AA as first step: charge-state distribution



$$P_{[n_b]} = \prod_b^{\text{bound}} \frac{e^{-(\varepsilon_b - \mu)n_b/T}}{1 + e^{-(\varepsilon_b - \mu)/T}} \Rightarrow P_Q = \sum_{[n_b]}^Q P_{[n_b]}$$

AA as first step: free-electron density



After averaging all possible
free-electron configurations

$$\rho_f(\mathbf{r}, T) = \sum_p^{\text{continuum}} |\psi_p(\mathbf{r})|^2 \bar{n}_p(\mu, T)$$

Second step: fixed-config. calculation

- > Connection between first step and second step
 - picking up one bound-electron configuration: most probable one
 - constructing a free-electron density
- > Performing a new SCF calculation with the fixed free-electron density

$$\hat{H} = -\frac{1}{2}\nabla^2 + V[\rho(\mathbf{r}; T)]$$

$$\rho(\mathbf{r}; T) = \underbrace{\sum_b^{\text{bound}} |\psi_b(\mathbf{r})|^2 n_b}_{\text{self-consistently updated}} + \underbrace{\sum_p^{\text{continuum}} |\psi_p(\mathbf{r})|^2 \bar{n}_p(\mu, T)}_{\text{fixed}}$$

2nd step: *K*-shell ionization & transition *E*

Al at $T=80$ eV

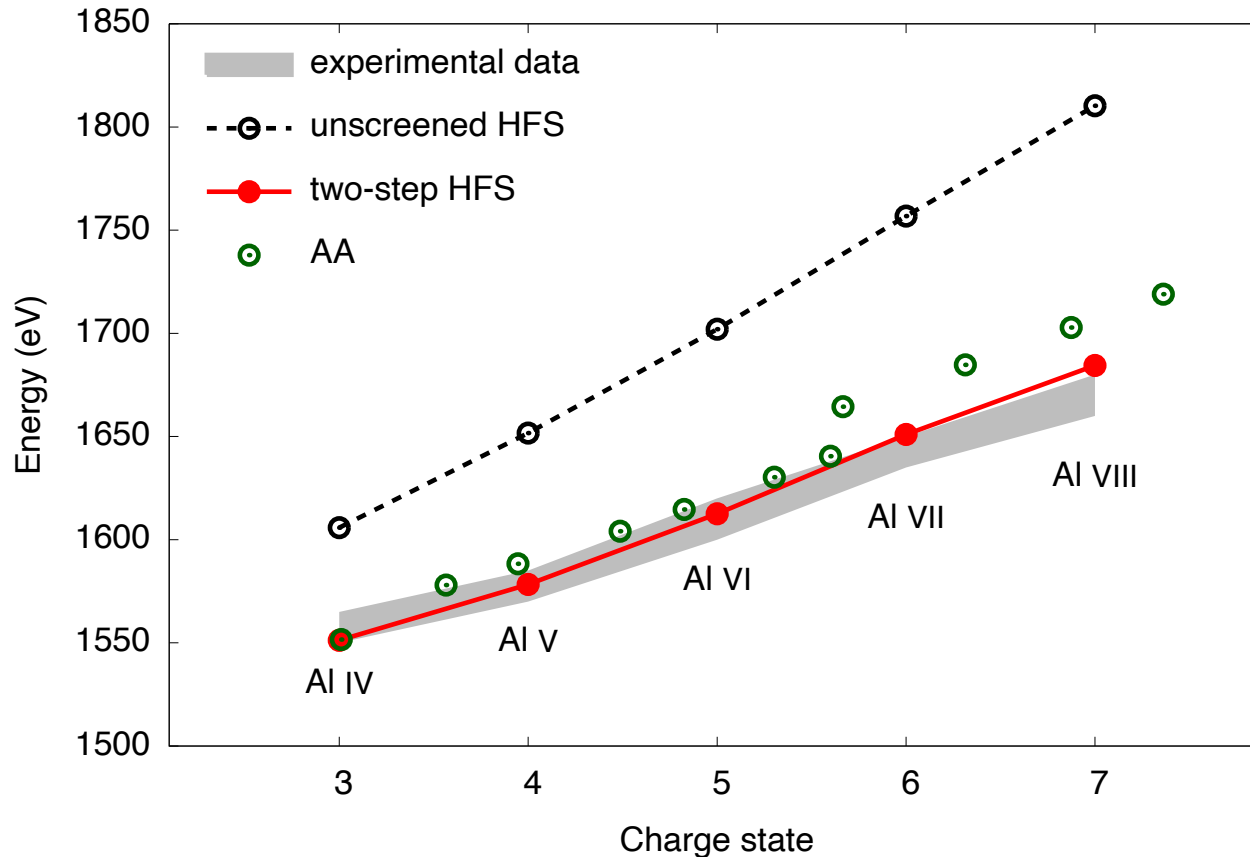
Q	Configuration	Probability	E_K	$E_{K\alpha}$
+5	$1s^2 2s^1 2p^4 3s^0 3p^1$	0.0193	1618.3	1497.7
	$1s^2 2s^2 2p^3 3s^0 3p^1$	0.0187	1623.1	1500.3
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	$1s^2 2s^0 2p^3 3s^0 3p^1$	0.0189	1699.3	1524.5
	$1s^2 2s^0 2p^4 3s^0 3p^0$	0.0175	1660.9	1509.9
	$1s^2 2s^1 2p^2 3s^1 3p^0$	0.0153	1705.4	1527.9
	$1s^2 2s^2 2p^1 3s^0 3p^1$	0.0120	1711.7	1531.2
+8	$1s^2 2s^1 2p^2 3s^0 3p^0$	0.0747	1718.7	1530.0
	$1s^2 2s^0 2p^3 3s^0 3p^0$	0.0342	1712.3	1526.7
	$1s^2 2s^1 2p^1 3s^0 3p^1$	0.0241	1758.5	1546.5
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	$1s^2 2s^1 2p^0 3s^0 3p^0$	0.0106	1835.2	1572.1

- SCF calculation for each config.
- individual configurations: different IPs and $K\alpha$ lines
- ground-state configuration $\neq$ the most probable configuration
- *M*-shell electrons do not alter the $K\alpha$ lines that much
 $\rightarrow K^n L^m$ labeling makes sense

cf) Iglesias, *HEDP* **12**, 5 (2014).

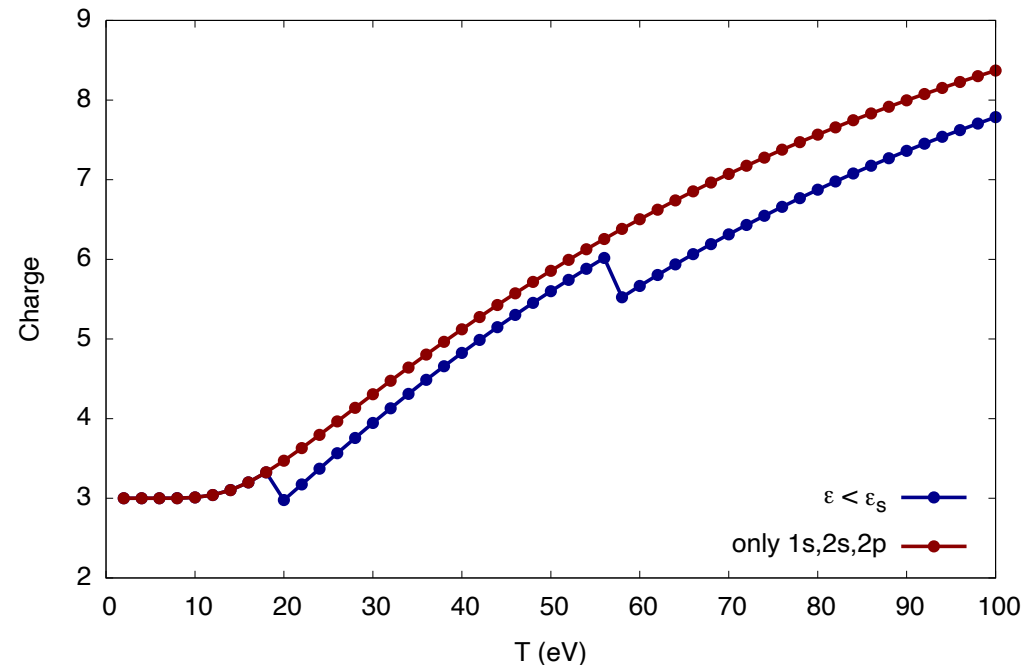
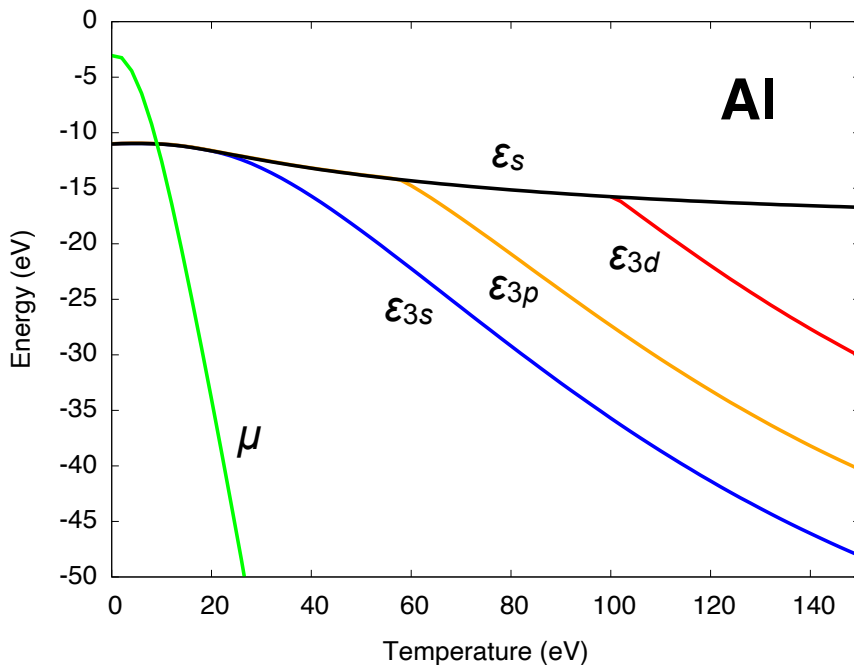
T	$\bar{Q}$	Q_{mp}	C_{mp}
10	+3.01	+3	$1s^2 2s^2 2p^6$
30	+3.95	+4	$1s^2 2s^2 2p^5$
40	+4.83	+5	$1s^2 2s^2 2p^4$
60	+5.67	+6	$1s^2 2s^2 2p^3$
80	+6.87	+7	$1s^2 2s^1 2p^3$

Ionization potential with two-step model



Son, Thiele, Jurek, Ziaja & Santra, *Phys. Rev. X* **4**, 031004 (2014).

How to define atomic charges in AA



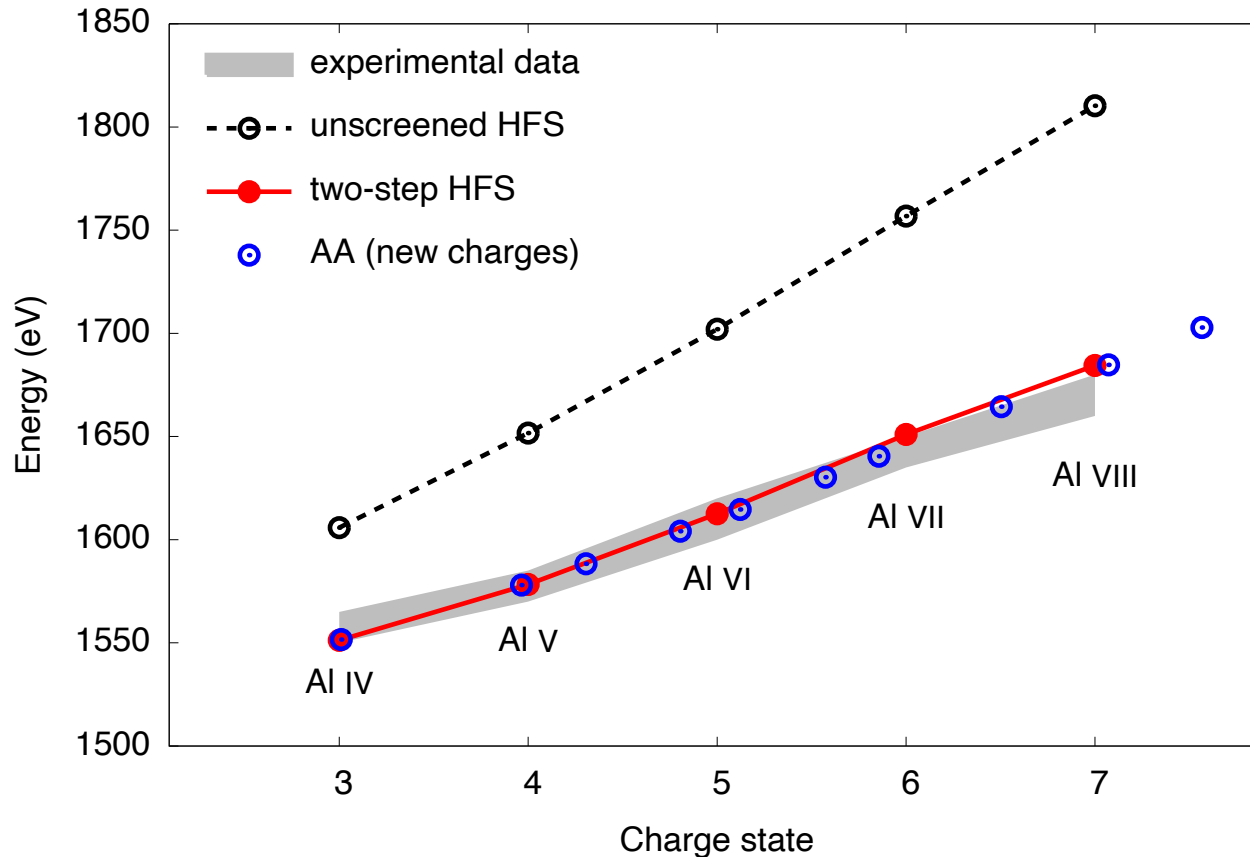
- $\varepsilon < \varepsilon_s$: bound
- $\varepsilon \geq \varepsilon_s$: (pseudo)continuum

Based on bound electron: $\bar{Q} = Z - \sum_p^{\varepsilon_p < \varepsilon_s} \frac{(4l_p + 2)}{e^{\beta(\varepsilon_p - \mu)} + 1}$

Bekx *et al.*, *Phys. Rev. Res.*
2, 033061 (2020).

$K^n L^m$ labelling: $\bar{Q}' = Z - \sum_{p=1s,2s,2p} \frac{(4l_p + 2)}{e^{\beta(\varepsilon_p - \mu)} + 1}$

Ionization potential with AA (new charges)



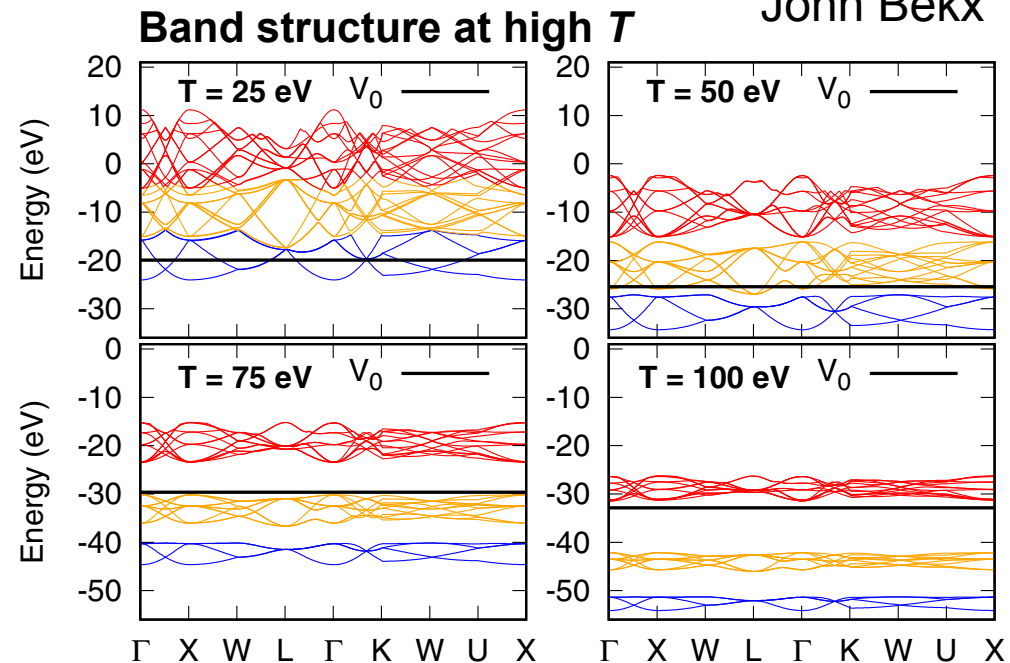
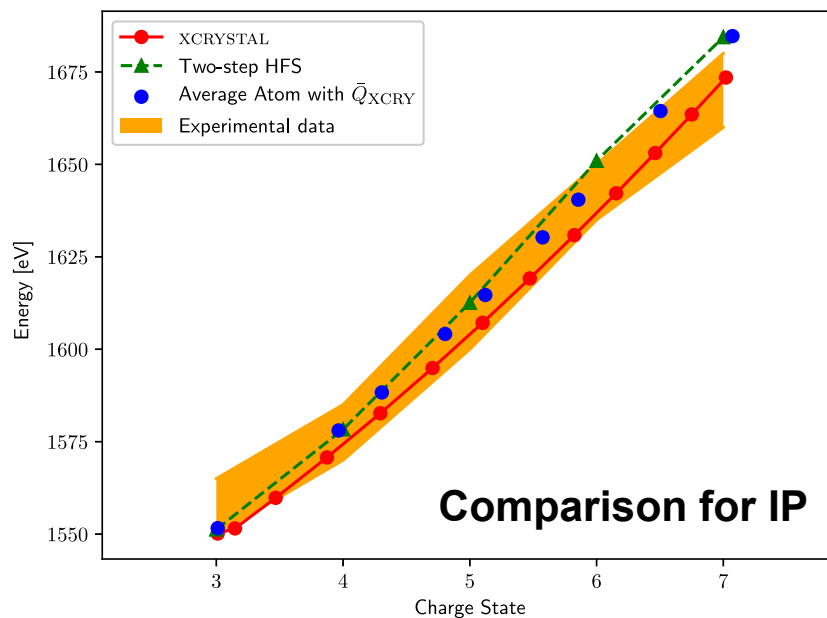
AA is applicable to predict IP values for different atomic charges

Beyond atomic picture: XCRYSTAL

- **XCRYSTAL**: finite-temperature HFS with the Bloch-wave approach within a periodic atomic lattice
- hybrid basis: localized core orbitals + plane wave
- no pseudopotential required



John Bekx



Bekx et al., *Phys. Rev. Res.* **2**, 033061 (2020).

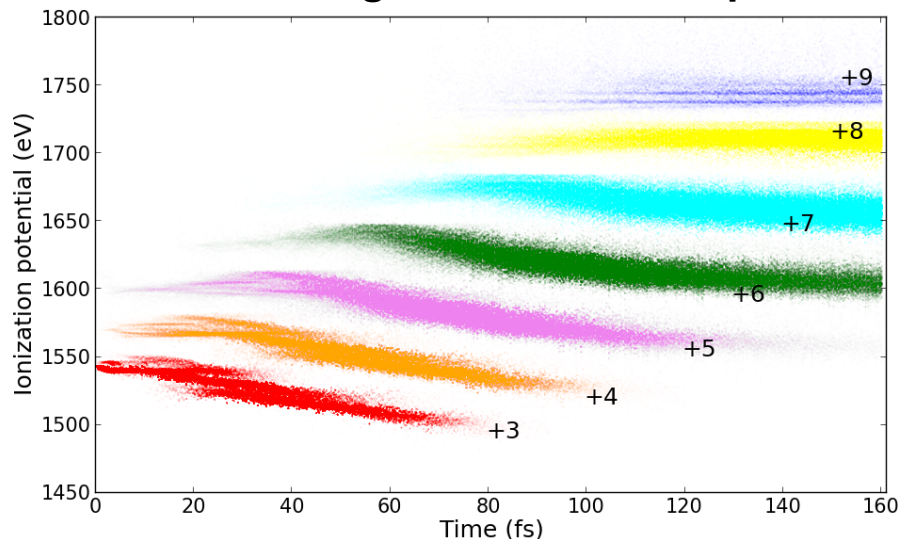
Beyond average picture: XMDYN + XPOT

- > **XMDYN**: quantum for bound electrons, classical for free electrons and ions → Monte-Carlo Molecular Dynamics (MCMD)
- > **XPOT**: enables quantum calculation with a plasma environment at any given time t → NLTE approach for IPD

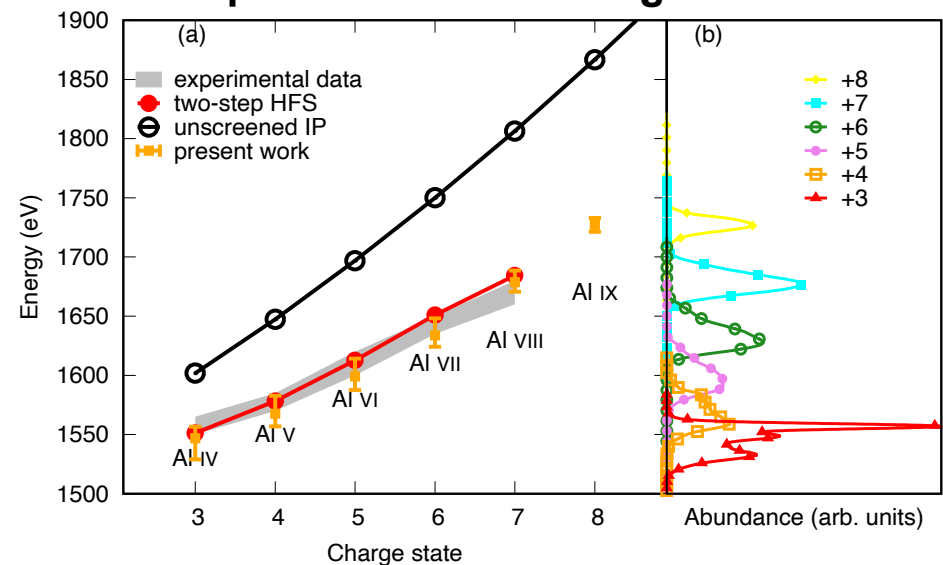


Rui Jin

Time-resolved IP: Al interacting with 80-fs XFEL pulse



Comparison for time-integrated IP



Jin *et al.*, *Phys. Rev. E* **103**, 023203 (2021).

Conclusion

- Two-step model: first-principles calculation combining average-atom model and fixed-configuration model
- Accurately and efficiently describes atomic properties within plasmas
- Focused on IPD effects of Al plasmas: good agreement with XFEL exp.
- New implementation for AA model within XATOM: simple and robust
- AA model: good description for IP & population analysis (e.g. CSD)
- Beyond AA model: finite-temperature crystalline calculation and non-thermal equilibrium simulation for studying transient IPD

Thank you for your attention!